

RELIABILITY REPORT

FOR

MAX4989ETD+

PLASTIC ENCAPSULATED DEVICES

March 24, 2009

# **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Approved by	
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Quality Assurance	
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## Conclusion

The MAX4989ETD+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

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#### I. Device Description

#### A. General

The MAX4989 is a bidirectional 2-of-4 USB 2.0 crosspoint switch. The MAX4989 features the low on-capacitance and low on-resistance necessary to switch USB 2.0 low-/full-/Hi-Speed signals at data rates up to 480Mbps. This device allows any 2-of-4 USB pairs to be connected together and is configured through a simple 3-input control logic interface. The MAX4989 operates from a single +2.7V to +5.5V supply and features an internal charge pump to permit full rail-to-rail swing. This device also features a high-impedance shutdown mode to reduce supply current to 100nA (typ). The MAX4989 is available in a 14-pin, 3mm x 3mm TDFN package and operates over the extended -40°C to +85°C temperature range.



## II. Manufacturing Information

A. Description/Function: USB 2.0 Hi-Speed 2 of 4 Crosspoint Switch

B. Process: S4
C. Number of Device Transistors: 886
D. Fabrication Location: California
E. Assembly Location: UTL Thailand
F. Date of Initial Production: March 19, 2009

## III. Packaging Information

A. Package Type: 14-pin TDFN 3x3

B. Lead Frame: Copper

C. Lead Finish: 100% matte Tin

D. Die Attach: Conductive Epoxy

E. Bondwire: Au (1.0 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: #

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity per Level 1

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 54°C/W
K. Single Layer Theta Jc: 8.3°C/W
L. Multi Layer Theta Ja: 41°C/W
M. Multi Layer Theta Jc: 8.3°C/W

#### IV. Die Information

A. Dimensions: 36 X 45 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub>/SiO<sub>2</sub> (Silicon nitride/ Silicon dioxide

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
 F. Minimum Metal Spacing: Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.
 H. Isolation Dielectric: SiO<sub>2</sub>
 I. Die Separation Method: Wafer Saw



## V. Quality Assurance Information

A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm</li>D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = 22.4 \times 10^{-9}$$

3 = 22.4 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at http://www.maxim-ic.com/. Current monitor data for the S4 Process results in a FIT Rate of 0.28 @ 25C and 4.85 @ 55C (0.8 eV, 60% UCL)

#### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

## C. E.S.D. and Latch-Up Testing

The AJ62 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500 V per JEDEC JESD22-A114-D. Latch-Up testing has shown that this device withstands a current of +/-100 mA, 1.5x VCCMax Overvoltage per JESD78.



# **Table 1**Reliability Evaluation Test Results

## MAX4989ETD+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C Biased	DC Parameters & functionality	48	0	
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
85/85	Ta = 85°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 1000hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	•			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data